

Day : Thursday  
 Date: 8/10/2006

Time: 05:40:45

**PALM INTRANET****Inventor Name Search Result**

Your Search was:

Last Name = SAKURADA

First Name = MASAHIRO

Application#	Patent#	Status	Date Filed	Title	Inventor Name
08498894	5609682	150	07/06/1995	A METHOD FOR THE PREPARATION OF SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
08565100	5667584	150	11/30/1995	METHOD FOR THE PREPARATION OF A SINGLE CRYSTAL OF SILICON WITH DECREASED CRYSTAL DEFECTS	SAKURADA, MASAHIRO
08655810	5817171	150	05/31/1996	APPARATUS AND METHOD FOR PRODUCING SINGLE CRYSTAL USING CZOCHRALSKI TECHNIQUE	SAKURADA, MASAHIRO
08660198	5728211	250	06/03/1996	SILICON SINGLE CRYSTAL WITH LOW DEFECT DENSITY AND METHOD OF PRODUCING SAME	SAKURADA, MASAHIRO
08666654	5704973	150	06/18/1996	AN APPARATUS AND METHOD FOR THE UNIFORM DISTRIBUTION OF CRYSTAL DEFECTS UPON A SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
08768282	5730800	150	12/17/1996	FUSED SILICA GLASS CRUCIBLE	SAKURADA, MASAHIRO
08798472	5948163	250	02/10/1997	APPARATUS FOR MANUFACTURING CRYSTALS ACCORDING TO THE CZOCHRALSKI METHOD, AND CRYSTALS MANUFACTURED BY THE MANUFACTURING METHOD	SAKURADA, MASAHIRO
09090400	5938842	150	06/04/1998	METHOD FOR PRODUCING A SINGLE CRYSTAL USING CZOCHRALSKI TECHNIQUE	SAKURADA, MASAHIRO

09125339	6071337	150	08/13/1998	APPARATUS AND METHOD FOR PRODUCING CRYSTALS BY THE CZOCHRALSKI METHOD AND CRYSTALS PRODUCED BY THIS METHOD	SAKURADA, MASAHIRO
09232561	6174364	150	01/15/1999	METHOD FOR PRODUCING SILICON MONOCRYSTAL AND SILICON MONOCRYSTAL WAFER	SAKURADA, MASAHIRO
09328278	6190452	150	06/08/1999	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING IT	SAKURADA, MASAHIRO
09646713	6565822	150	09/21/2000	EPITAXIAL SILICON WAFER, METHOD FOR PRODUCING THE SAME AND SUBSTRATE FOR EPITAXIAL SILICON WAFER	SAKURADA, MASAHIRO
09727275	6482260	150	11/30/2000	SILICON SINGLE CRYSTAL WAFER AND A METHOD FOR PRODUCING IT	SAKURADA, MASAHIRO
10204935	6913646	150	08/27/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
10312921	6893499	150	12/26/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR MANUFACTURING THE SAME	SAKURADA, MASAHIRO
10500580	Not Issued	93	07/01/2004	AN SOI WAFER AND A METHOD FOR PRODUCING AN SOI WAFER	SAKURADA, MASAHIRO
10512470	Not Issued	30	10/26/2004	A SILICON SINGLE CRYSTAL WAFER, AN EPITAXIAL WAFER AND A METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
10516347	Not Issued <i>App.</i>	30 <i>conts</i>	11/30/2004 <i>Inventor</i>	GRAPHITE HEATER FOR PRODUCING SINGLE CRYSTAL, APPARATUS FOR PRODUCING SINGLE CRYSTAL, AND METHOD FOR PRODUCING SINGLE CRYSTAL	SAKURADA, MASAHIRO
10530557	Not Issued	20	04/07/2005	Annealed wafer and method for manufacturing the same	SAKURADA, MASAHIRO

<a href="#"><u>10538878</u></a>	Not Issued	41	06/14/2005	Method of producing p-doped silicon single crystal and p-doped n-type silicon single crystal wafer	SAKURADA, MASAHIRO
<a href="#"><u>10542376</u></a>	Not Issued	30	07/14/2005	AN SOI WAFER AND A METHOD FOR PRODUCING THE SAME	SAKURADA, MASAHIRO
<a href="#"><u>10546693</u></a>	Not Issued	25	08/22/2005	An soi wafer and a method for producing the same	SAKURADA, MASAHIRO
<a href="#"><u>10560581</u></a>	Not Issued	19	01/01/0001	Method for producing a single crystal and a single crystal	SAKURADA, MASAHIRO
<a href="#"><u>10561205</u></a>	Not Issued	25	02/03/2006	Process for producing single crystal and single crystal	SAKURADA, MASAHIRO
<a href="#"><u>10561865</u></a>	Not Issued	41	02/20/2006	Method for producing single crystal and single crystal	SAKURADA, MASAHIRO

Inventor Search Completed: No Records to Display.

<b>Search Another: Inventor</b>	<b>Last Name</b>	<b>First Name</b>
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**PALM INTRANET****Inventor Name Search Result**

Your Search was:

Last Name = FUSEGAWA

First Name = IZUMI

Application#	Patent#	Status	Date Filed	Title	Inventor Name
<a href="#">06941624</a>	Not Issued	161	12/11/1986	METHOD AND APPARATUS FOR CZOCHRALSKI SINGLE CRYSTAL GROWING	FUSEGAWA, IZUMI
<a href="#">07242414</a>	4956153	250	09/09/1988	APPARATUS FOR CZOCHRALSKI SINGLE CRYSTAL GROWING	FUSEGAWA, IZUMI
<a href="#">07496750</a>	5110404	150	03/21/1990	METHOD FOR HEAT PROCESSING OF SILICON	FUSEGAWA, IZUMI
<a href="#">07703750</a>	Not Issued	166	05/21/1991	METHOD FOR PULLING UP SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
<a href="#">07713848</a>	5306387	150	06/12/1991	METHOD FOR PULLING UP SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
<a href="#">07729026</a>	Not Issued	161	07/12/1991	METHOD FOR PULLING SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
<a href="#">07796385</a>	5688319	150	11/22/1991	METHOD FOR TESTING ELECTRICAL PROPERTIES OF SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<a href="#">07850506</a>	5262338	250	03/13/1992	METHOD FOR FABRICATION OF SEMICONDUCTOR DEVICE	FUSEGAWA, IZUMI
<a href="#">07850915</a>	Not Issued	166	03/13/1992	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
<a href="#">07850916</a>	5386796	150	03/13/1992	METHOD FOR TESTING QUALITY OF SILICON WAFER	FUSEGAWA, IZUMI
<a href="#">07852612</a>	5248378	150	03/17/1992	METHOD AND APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<a href="#">07953918</a>	5359959	150	09/30/1992	METHOD FOR PULLING UP	FUSEGAWA, IZUMI

SEMI-CONDUCTOR SINGLE CRYSTAL					
07961182	5462010	250	10/14/1992	APPARATUS FOR SUPPLYING GRANULAR RAW MATERIAL FOR A SEMICONDUCTOR SINGLE CRYSTAL PULLING APPARATUS	FUSEGAWA, IZUMI
07961764	5373805	250	10/15/1992	SINGLE CRYSTAL PULLING APPARATUS	FUSEGAWA, IZUMI
08011744	5340434	250	02/01/1993	PROCESS FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
08012172	5361721	250	02/02/1993	SINGLE CRYSTAL PULLING APPARATUS	FUSEGAWA, IZUMI
08108285	Not Issued	166	08/19/1993	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
08190604	Not Issued	166	02/02/1994	CRUCIBLE FOR PULLING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
08238722	5534112	150	05/05/1994	METHOD FOR TESTING ELECTRICAL PROPERTIES OF SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
08293214	Not Issued	166	08/19/1994	APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL GROWN BY CZOCHRALSKI METHOD	FUSEGAWA, IZUMI
08395837	5501172	150	02/28/1995	METHOD OF GROWING SILICON SINGLE CRYSTALS	FUSEGAWA, IZUMI
08445029	Not Issued	166	05/19/1995	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
08510436	5720809	250	08/02/1995	CRUCIBLE FOR PULLING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
08552164	Not Issued	166	11/02/1995	APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL GROWN BY CZOCHRALSKI METHOD	FUSEGAWA, IZUMI
08699719	5725661	250	07/01/1996	EQUIPMENT FOR PRODUCING SILICON SINGLE CRYSTALS	FUSEGAWA, IZUMI
08754784	5938841	150	11/21/1996	DEVICE FOR PRODUCING SINGLE CRYSTAL	FUSEGAWA, IZUMI
08760959	5766346	150	12/05/1996	APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
08770499	5851283	150	12/20/1996	METHOD AND APPARATUS	FUSEGAWA, IZUMI

				FOR PRODUCTION OF SINGLE CRYSTAL	
<u>08773351</u>	5871583	150	12/26/1996	AN APPARATUS FOR PRODUCING SILICON CRYSTAL	FUSEGAWA, IZUMI
<u>08916291</u>	5834322	250	08/22/1997	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>09270277</u>	6153009	150	03/16/1999	METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL AND THE SILICON SINGLE CRYSTAL PRODUCED THEREBY	FUSEGAWA, IZUMI
<u>09290261</u>	6117231	150	04/13/1999	METHOD OF MANUFACTURING SEMICONDUCTOR SILICON SINGLE CRYSTAL WAFER	FUSEGAWA, IZUMI
<u>09429343</u>	6387466	150	10/28/1999	SINGLE-CRYSTAL SILICON WAFER	FUSEGAWA, IZUMI
<u>09646713</u>	6565822	150	09/21/2000	EPITAXIAL SILICON WAFER, METHOD FOR PRODUCING THE SAME AND SUBSTRATE FOR EPITAXIAL SILICON WAFER	FUSEGAWA, IZUMI
<u>09673480</u>	Not Issued	161	10/16/2000	Method for producing silicon single crystals	FUSEGAWA, IZUMI
<u>09674858</u>	6423285	150	11/07/2000	Method for producing silicon single crystal and production apparatus therefor as well as crystal and silicon wafer produced by the method	FUSEGAWA, IZUMI
<u>09937132</u>	6632280	150	09/21/2001	SINGLE CRYSTAL GROWING DEVICE	FUSEGAWA, IZUMI
<u>09959381</u>	6592662	150	10/24/2001	METHOD FOR PREPARING SILICON SINGLE CRYSTAL AND SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>09979519</u>	6632411	150	11/23/2001	SILICON WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>10204278</u>	6764548	150	08/20/2002	APPARATUS AND METHOD FOR PRODUCING SILICON SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>10204935</u>	6913646	150	08/27/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING SILICON	FUSEGAWA, IZUMI

SINGLE CRYSTAL					
10312921	6893499	150	12/26/2002	SILICON SINGLE CRYSTAL WAFER AND A METHOD FOR MANUFACTURING THE SAME	FUSEGAWA, IZUMI
10500580	Not Issued	93	07/01/2004	AN SOI WAFER AND A METHOD FOR PRODUCING AN SOI WAFER	FUSEGAWA, IZUMI
10510695	Not Issued	41	10/08/2004	METHOD OF MANUFACTURING SILICON SINGLE CRYSTAL, SILICON SINGLE CRYSTAL AND SILICON WAFER	FUSEGAWA, IZUMI
10512470	Not Issued	30	10/26/2004	A SILICON SINGLE CRYSTAL WAFER, AN EPITAXIAL WAFER AND A METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
10516347	Not Issued <i>Ref. to Inventor</i>	30	11/30/2004	GRAPHITE HEATER FOR PRODUCING SINGLE CRYSTAL, APPARATUS FOR PRODUCING SINGLE CRYSTAL, AND METHOD FOR PRODUCING SINGLE CRYSTAL	FUSEGAWA, IZUMI
10538878	Not Issued	41	06/14/2005	Method of producing p-doped silicon single crystal and p-doped n-type silicon single crystal wafer	FUSEGAWA, IZUMI
10542376	Not Issued	30	07/14/2005	AN SOI WAFER AND A METHOD FOR PRODUCING THE SAME	FUSEGAWA, IZUMI
10561865	Not Issued	41	02/20/2006	Method for producing single crystal and single crystal	FUSEGAWA, IZUMI
10568186	Not Issued	20	03/03/2006	Process for producing single crystal and silicon crystal wafer	FUSEGAWA, IZUMI

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**PALM INTRANET****Inventor Name Search Result**

Your Search was:

Last Name = SOETA

First Name = SATOSHI

Application#	Patent#	Status	Date Filed	Title	Inventor Name
08759223	5888298	150	12/05/1996	MEMBER-HANDLING MECHANISM, AND MEMBER-HANDLING JIG FOR A CRYSTAL PULLING APPARATUS	SOETA, SATOSHI
08776776	5972106	150	02/10/1997	DEVICE AND METHOD FOR PRODUCING SINGLE CRYSTAL	SOETA, SATOSHI
08804146	5851287	150	02/20/1997	SEED CRYSTAL HOLDER	SOETA, SATOSHI
09508695	6280522	150	03/29/2000	QUARTZ GLASS CRUCIBLE FOR PULLING SILICON SINGLE CRYSTAL AND PRODUCTION PROCESS FOR SUCH CRUCIBLE	SOETA, SATOSHI
10516347	Not Issued	30	11/30/2004	GRAPHITE HEATER FOR PRODUCING SINGLE CRYSTAL, APPARATUS FOR PRODUCING SINGLE CRYSTAL, AND METHOD FOR PRODUCING SINGLE CRYSTAL	SOETA, SATOSHI

Inventor Search Completed: No Records to Display.

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**PALM INTRANET**
**Inventor Name Search Result**

Your Search was:

Last Name = IIDA

First Name = MAKOTO

<b>Application#</b>	<b>Patent#</b>	<b>Status</b>	<b>Date Filed</b>	<b>Title</b>	<b>Inventor Name</b>
05810759	4163215	150	06/28/1977	SAFETY LOCK SYSTEM	IIDA, MAKOTO
05895605	4227577	150	04/12/1978	FIRE-EXTINGUISHING SYSTEM	IIDA, MAKOTO
06336323	4409341	150	12/31/1981	COMPOSITION FOR FIRE RETARDANT URETHANE FOAM	IIDA, MAKOTO
06880012	4734448	150	06/30/1986	PROPYLENE POLYMER COMPOSITION	IIDA, MAKOTO
07219267	Not Issued	166	07/15/1988	ELECTROCONDUCTIVE RESIN COMPOSITION FOR MOLDING AND ELECTROMAGNETIC WAVE INTERFERENCE SHIELD STRUCTURE MOLDED FROM THE COMPOSITION	IIDA, MAKOTO
07538113	5071223	150	06/14/1990	CIRCUIT STRUCTURE FORMED BY INSERT MOLDING OF ELECTRIC AND/OR OPTICAL TRANSMISSION MEDIUM	IIDA, MAKOTO
07592545	Not Issued	166	10/02/1990	FOCUS DRAW-IN METHOD FOR OPTICAL DISC DEVICE	IIDA, MAKOTO
07769348	6156427	250	10/02/1991	ELECTROCONDUCTIVE RESIN COMPOSITION FOR MOLDING AND ELECTROMAGNETIC WAVE INTERFERENCE SHIELD STRUCTURE MOLDED FROM THE COMPOSITION	IIDA, MAKOTO
07785000	5179601	150	10/30/1991	METHOD OF MANUFACTURING CIRCUIT STRUCTURE BY INSERT MOLDING OF ELECTRIC AND/OR OPTICAL TRANSMISSION MEDIUM	IIDA, MAKOTO

<u>07866166</u>	Not Issued	166	06/29/1992	OPTICAL DISK SYSTEM	IIDA, MAKOTO
<u>07939045</u>	Not Issued	166	09/03/1992	FOCUS DRAW-IN SYSTEM FOR OPTICAL DISC DEVICE	IIDA, MAKOTO
<u>08137211</u>	5414682	150	10/18/1993	FOCUS DRAW-IN SYSTEM FOR OPTICAL DISC DEVICE	IIDA, MAKOTO
<u>08172413</u>	5491301	150	12/22/1993	SHIELDING METHOD AND CIRCUIT BOARD EMPLOYING THE SAME	IIDA, MAKOTO
<u>08279318</u>	5461599	150	07/22/1994	OPTICAL DISK SYSTEM	IIDA, MAKOTO
<u>08809295</u>	Not Issued	161	03/27/1997	PROPYLENE RESIN COMPOSITION FOR AUTOMOTIVE INTERIOR PARTS, AND AUTOMOTIVE INTERIOR PARTS	IIDA, MAKOTO
<u>08827060</u>	Not Issued	161	03/26/1997	PRESS WORKING METHOD AND EQUIPMENT THEREFOR	IIDA, MAKOTO
<u>08915397</u>	5871578	150	08/20/1997	METHODS FOR HOLDING AND PULLING SINGLE CRYSTAL	IIDA, MAKOTO
<u>08923963</u>	5911821	150	09/05/1997	METHOD OF HOLDING A MONOCRYSTAL, AND METHOD OF GROWING THE SAME	IIDA, MAKOTO
<u>08929670</u>	5964941	150	09/15/1997	CRYSTAL PULLING METHOD AND APPARATUS	IIDA, MAKOTO
<u>08944869</u>	5882397	150	10/06/1997	CRYSTAL PULLING METHOD	IIDA, MAKOTO
<u>09039830</u>	6053975	150	03/16/1998	CRYSTAL HOLDING APPARATUS	IIDA, MAKOTO
<u>09101941</u>	6120749	150	07/17/1998	SILICON SINGLE CRYSTAL WITH NO CRYSTAL DEFECT IN PERIPHERAL PART OF WAFER AND PROCESS FOR PRODUCING THE SAME	IIDA, MAKOTO
<u>09109530</u>	5968264	150	07/02/1998	METHOD AND APPARATUS FOR MANUFACTURING A SILICON SINGLE CRYSTAL HAVING FEW CRYSTAL DEFECTS, AND A SILICON SINGLE CRYSTAL AND SILICON WAFERS MANUFACTURED BY THE SAME	IIDA, MAKOTO
<u>09140288</u>	5948164	250	08/25/1998	SEED CRYSTAL HOLDER	IIDA, MAKOTO

09173931	6027562	150	10/16/1998	METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL HAVING FEW CRYSTAL DEFECTS, AND A SILICON SINGLE CRYSTAL AND SILICON WAFERS PRODUCED BY THE METHOD	IIDA, MAKOTO
09188490	6066306	150	11/09/1998	SILICON SINGLE CRYSTAL WAFER HAVING FEW CRYSTAL DEFECTS, AND METHOD FOR PRODUCING THE SAME	IIDA, MAKOTO
09194232	6445872	150	11/23/1998	RECORDING AND REPRODUCING APPARATUS FOR RECORDING DIGITAL BROADCAST COMPRESSION-CODED DATA OF VIDEO SIGNALS OF A MULTIPLICITY OF CHANNELS	IIDA, MAKOTO
09197130	6048395	150	11/20/1998	METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL HAVING FEW CRYSTAL DEFECTS	IIDA, MAKOTO
09264514	6191009	150	03/08/1999	METHOD FOR PRODUCING SILICON SINGLE CRYSTAL WAFER AND SILICON SINGLE CRYSTAL WAFER	IIDA, MAKOTO
09294323	6191675	150	04/20/1999	HIGH VOLTAGE TRANSFORMER AND IGNITION TRANSFORMER USING THE SAME	IIDA, MAKOTO
09313856	6299982	150	05/18/1999	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL WAFER	IIDA, MAKOTO
09318055	6077343	150	05/25/1999	SILICON SINGLE CRYSTAL WAFER HAVING FEW DEFECTS WHEREIN NITROGEN IS DOPED AND A METHOD FOR PRODUCING IT	IIDA, MAKOTO
09329615	6197109	150	06/10/1999	METHOD FOR PRODUCING LOW DEFECT SILICON SINGLE CRYSTAL DOPED WITH NITROGEN	IIDA, MAKOTO
09359078	6159438	150	07/22/1999	METHOD AND APPARATUS FOR MANUFACTURING A	IIDA, MAKOTO

				SILICON SINGLE CRYSTAL HAVING FEW CRYSTAL DEFECTS, AND A SILICON SINGLE CRYSTAL AND SILICON WAFERS MANUFACTURED BY THE SAME	
<u>09454841</u>	6120599	150	12/06/1999	SILICON SINGLE CRYSTAL WAFER HAVING FEW CRYSTAL DEFECTS, AND METHOD FOR PRODUCING THE SAME	IIDA, MAKOTO
<u>09459849</u>	6120598	150	12/13/1999	METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL HAVING FEW CRYSTAL DEFECTS, AND A SILICON SINGLE CRYSTAL AND SILICON WAFERS PRODUCED BY THE METHOD	IIDA, MAKOTO
<u>09492001</u>	6348180	150	01/26/2000	SILICON SINGLE CRYSTAL WAFER HAVING FEW CRYSTAL DEFECTS	IIDA, MAKOTO
<u>09572788</u>	6780067	150	05/17/2000	COMBINED INTEGRAL MOLDED PRODUCT USING PRE-MOLDED MEMBER	IIDA, MAKOTO
<u>09577252</u>	6261361	150	05/19/2000	Silicon single crystal wafer having few defects wherein nitrogen is doped and a method for producing it	IIDA, MAKOTO
<u>09600033</u>	6334896	150	07/11/2000	SINGLE-CRYSTAL SILICON WAFER HAVING FEW CRYSTAL DEFECTS AND METHOD FOR MANUFACTURING THE SAME	IIDA, MAKOTO
<u>09661985</u>	6364947	150	09/14/2000	Method and apparatus for manufacturing a silicon single crystal Having few crystal defects, and a silicon single crystal and silicon wafers manufactured by the same	IIDA, MAKOTO
<u>09828206</u>	6401643	250	04/09/2001	SEWN COVER ASSEMBLY AND PRODUCT FOAMED THEREWITH	IIDA, MAKOTO
<u>09830386</u>	6544332	150	04/26/2001	METHOD FOR MANUFACTURING SILICON SINGLE CRYSTAL, SILICON SINGLE CRYSTAL	IIDA, MAKOTO

				MANUFACTURED BY THE METHOD, AND SILICON WAFER	
09868058	6548035	150	06/14/2001	SILICON SINGLE CRYSTAL WAFER FOR EPITAXIAL WAFER, EPITAXIAL WAFER, AND METHODS FOR PRODUCING THE SAME AND EVALUATING THE SAME	IIDA, MAKOTO
09869912	6843847	150	07/09/2001	SILICON SINGLE CRYSTAL WAFER, METHOD FOR PRODUCING THE SAME AND SOI WAFER	IIDA, MAKOTO
09869932	6544490	150	07/09/2001	SILICON WAFER AND PRODUCTION METHOD THEREOF AND EVALUATION METHOD FOR SILICON WAFER	IIDA, MAKOTO
09884784	Not Issued	161	06/19/2001	Hybrid housing of metal board and synthetic resin	IIDA, MAKOTO
09936920	6599360	150	09/20/2001	SILICON WAFER, METHOD FOR DETERMINING PRODUCTION CONDITIONS OF SILICON SINGLE CRYSTAL AND METHOD FOR PRODUCING SILICON WAFER	IIDA, MAKOTO
10009910	Not Issued	123	12/12/2001	Silicon wafer, silicon epitaxial wafer, anneal wafer and method for producing them	IIDA, MAKOTO
10130431	6841450	150	05/17/2002	ANNEALED WAFER MANUFACTURING METHOD AND ANNEALED WAFER	IIDA, MAKOTO

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